

Figure 1A

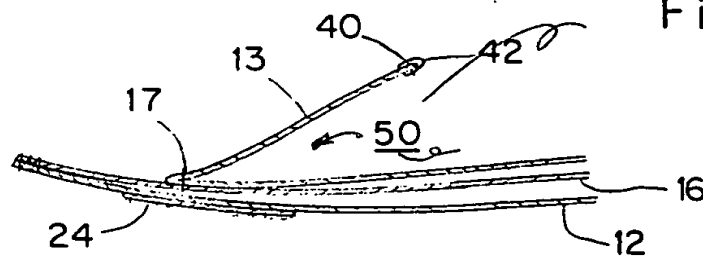


Figure 1B

Figure 5

Figure 5B

A cross-sectional view of a semiconductor device 500. The device features a substrate 1 with a top layer 163. On the left side, there is a curved structure 104A, and on the right side, there is a curved structure 104B. In the center, there is a vertical structure 404. Below structure 404, there is a horizontal dashed line 403. The entire device is labeled 500.